BGA2716

MMIC wideband amplifier

Rev. 3 — 8 September 2011

Product data sheet

1. Product profile

1.1 General description

Silicon Monolithic Microwave Integrated Circuit (MMIC) wideband amplifier with internal matching circuit in a 6-pin SOT363 SMD plastic package.

1.2 Features and benefits

- Internally matched to 50 Ω
- Wide frequency range (3.2 GHz at 3 dB bandwidth)
- Flat 23 dB gain (± 1 dB up to 2.7 GHz)
- 9 dBm output power at 1 dB compression point
- Good linearity for low current (IP3$_{out}$ = 22 dBm)
- Low second harmonic; -38 dBc at $P_L = -5$ dBm
- Unconditionally stable (K $\geq$ 1.2).

1.3 Applications

- LNB IF amplifiers
- Cable systems
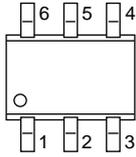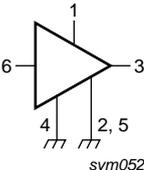- ISM
- General purpose.

1.4 Quick reference data

Table 1.   Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_S	DC supply voltage		-	5	6	V
I_S	supply current		-	15.9	-	mA
$\lvert s_{21} \rvert^2$	insertion power gain	f = 1 GHz	-	22.9	-	dB
NF	noise figure	f = 1 GHz	-	5.3	-	dB
$P_{L(sat)}$	saturated load power	f = 1 GHz	-	11.6	-	dBm

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
1	V_S		
2, 5	GND2		
3	RF_OUT		
4	GND1		
6	RF_IN		

3. Ordering information

Table 3. Ordering information

Type number	Package		Version
	Name	**Description**	
BGA2716	-	plastic surface mounted package; 6 leads	SOT363

4. Marking

Table 4. Marking

Type number	Marking code
BGA2716	B7-

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_S	DC supply voltage	RF input AC coupled	-	6	V
I_S	supply current		-	30	mA
P_{tot}	total power dissipation	$T_{sp} \leq 90\ °C$	-	200	mW
T_{stg}	storage temperature		−65	+150	°C
T_j	junction temperature		-	150	°C
P_D	maximum drive power		-	−10	dBm

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6. Thermal characteristics

Table 6.   Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	P_{tot} = 200 mW; $T_{sp} \leq$ 90 °C	300	K/W

7. Characteristics

Table 7.   Characteristics

V_S = 5 V; I_S = 15.9 mA; T_j = 25 °C; measured on demo board; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_S	supply current		13	15.9	21	mA
$\lvert s_{21} \rvert^2$	insertion power gain	f = 100 MHz	21	22.1	23	dB
		f = 1 GHz	22	22.9	24	dB
		f = 1.8 GHz	22	23.1	25	dB
		f = 2.2 GHz	21	22.8	24	dB
		f = 2.6 GHz	20	22.1	24	dB
		f = 3 GHz	19	20.8	22	dB
$\lvert s_{11} \rvert^2$	input return losses	f = 1 GHz	15	17	-	dB
		f = 2.2 GHz	10	12	-	dB
$\lvert s_{22} \rvert^2$	output return losses	f = 1 GHz	10	12	-	dB
		f = 2.2 GHz	9	11	-	dB
$\lvert s_{12} \rvert^2$	isolation	f = 1.6 GHz	30	31	-	dB
		f = 2.2 GHz	33	35	-	dB
NF	noise figure	f = 1 GHz	-	5.3	5.4	dB
		f = 2.2 GHz	-	5.5	5.6	dB
B	bandwidth	at $\lvert s_{21} \rvert^2$ −3 dB below flat gain at 1 GHz	3	3.2	-	GHz
K	stability factor	f = 1 GHz	-	1.4	-	
		f = 2.2 GHz	-	1.9	-	
$P_{L(sat)}$	saturated load power	f = 1 GHz	10	11.6	-	dBm
		f = 2.2 GHz	6	7.5	-	dBm
$P_{L(1dB)}$	load power	at 1 dB gain compression; f = 1 GHz	8	8.9	-	dBm
		at 1 dB gain compression; f = 2.2 GHz	5	6.1	-	dBm
IM2	second order intermodulation product	at P_L = −5 dBm; f_0 = 1 GHz	36	38	-	dBc
$IP3_{in}$	input, third order intercept point	f = 1 GHz	−2	−0.7	-	dBm
		f = 2.2 GHz	−8	−6.9	-	dBm
$IP3_{out}$	output, third order intercept point	f = 1 GHz	21	22.2	-	dBm
		f = 2.2 GHz	15	15.9	-	dBm

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8.   Application information

Figure 1 shows a typical application circuit for the BGA2716 MMIC. The device is internally matched to 50 Ω, and therefore does not need any external matching. The value of the input and output DC blocking capacitors C2 and C3 should not be more than 100 pF for applications above 100 MHz. However, when the device is operated below 100 MHz, the capacitor value should be increased.

The nominal value of the RF choke L1 is 100 nH. At the frequencies below 100 MHz this value should be increased. At frequencies above 1 GHz, a lower value can be used to tune the output return loss. For optimal results, a good quality chip inductor or a wire-wound SMD type should be chosen.

Both the RF choke and the 22 nF supply decoupling capacitor C1 should be located as close as possible to the MMIC.

The printed-circuit board (PCB) top ground plane, connected to pins 2, 4 and 5 must be as close as possible to the MMIC, and ideally directly beneath it. When using via holes, use multiple via holes, located as close as possible to the MMIC.
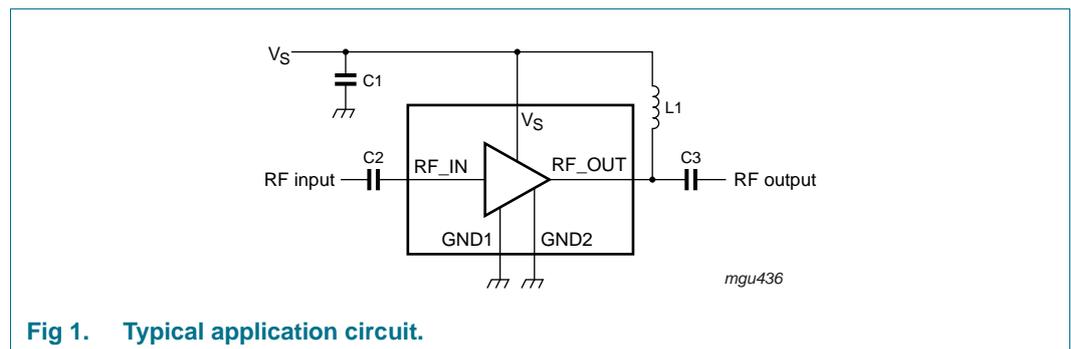
Fig 1.   Typical application circuit.

Figure 2 shows the PCB layout, used for the standard demonstration board.

Material = FR4; thickness = 0.6 mm, ε_r = 4.6.

Fig 2. **PCB layout and demonstration board showing components.**
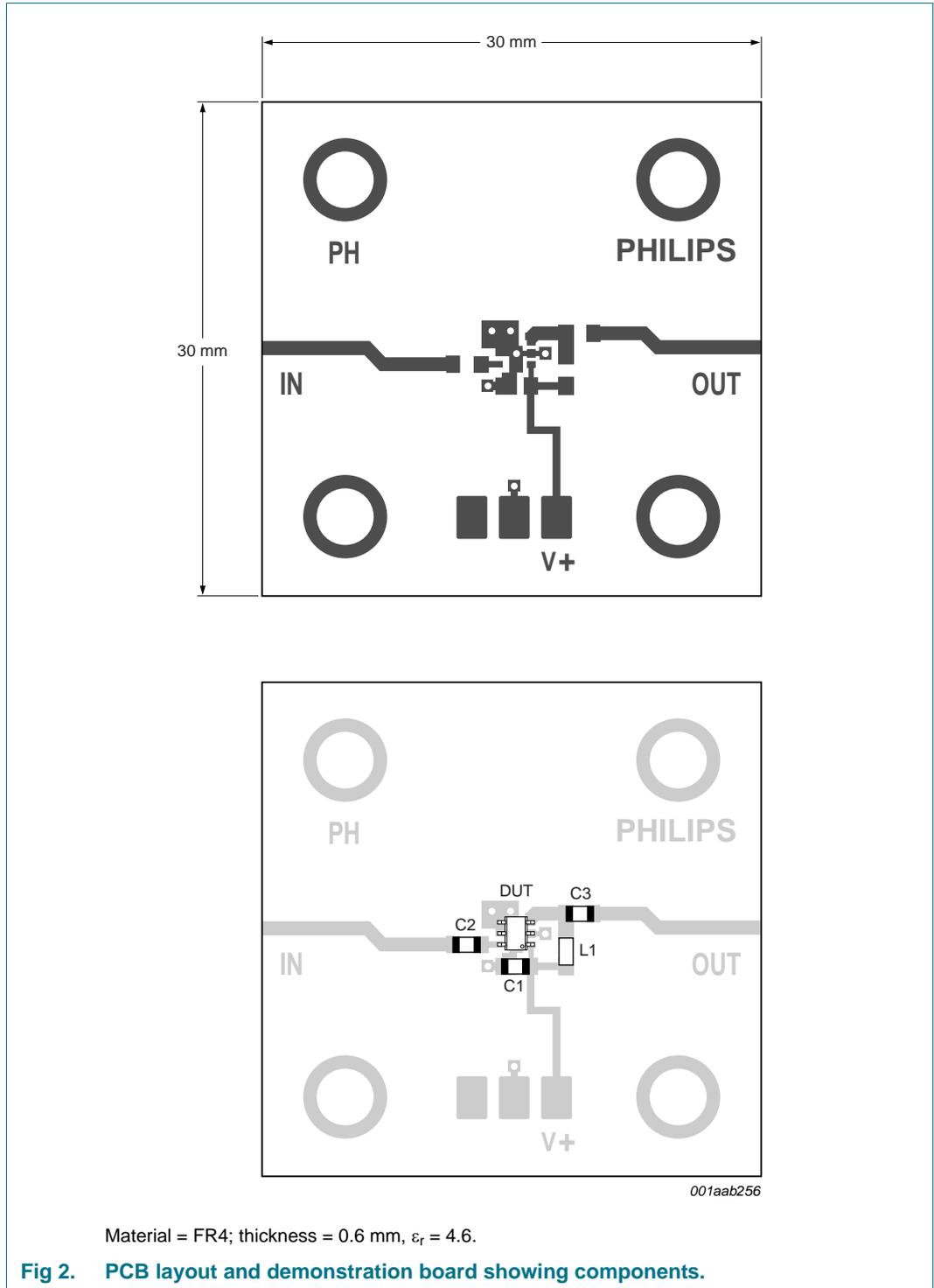
8.1 Application examples

The excellent wideband characteristics of the MMIC make it an ideal building block in IF amplifier such as LNBs (see Figure 3).

As second amplifier after an LNA, the MMIC offers an easy matching, low noise solution (see Figure 4).

As driver amplifier in the TX path, the good linear performance and matched input/output offer quick design solutions (see Figure 5).

Fig 3.   Application as IF amplifier.

Fig 4.   Application as RF amplifier.

Fig 5.   Application as driver amplifier.

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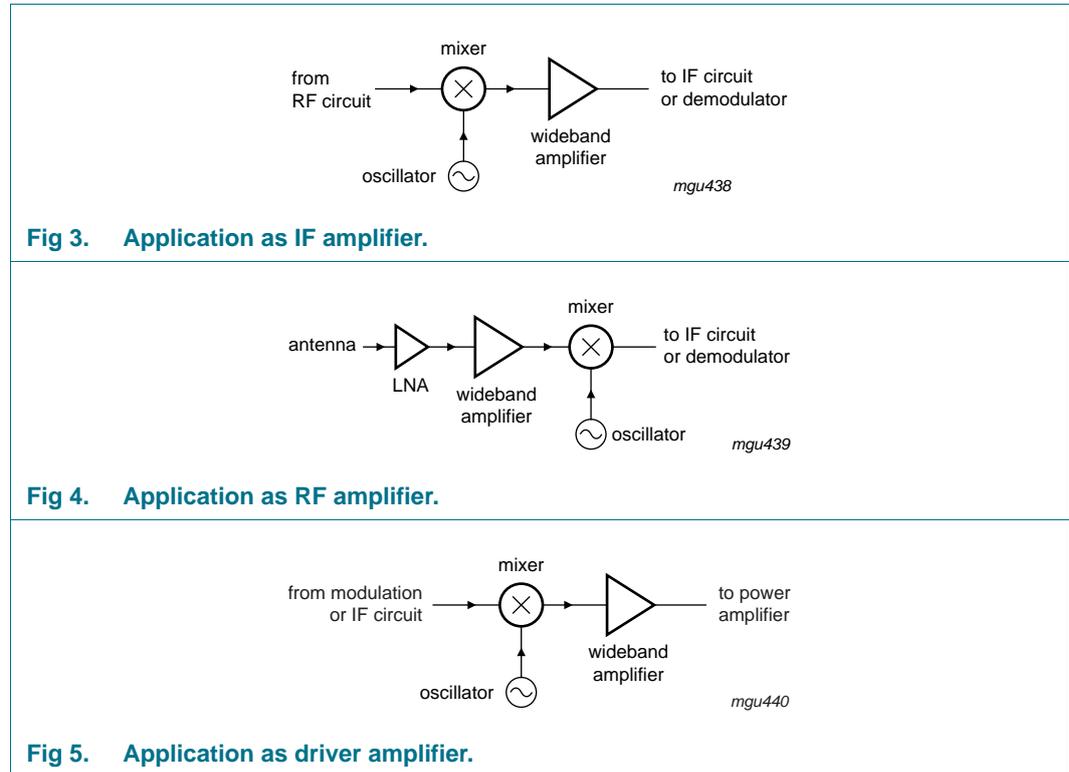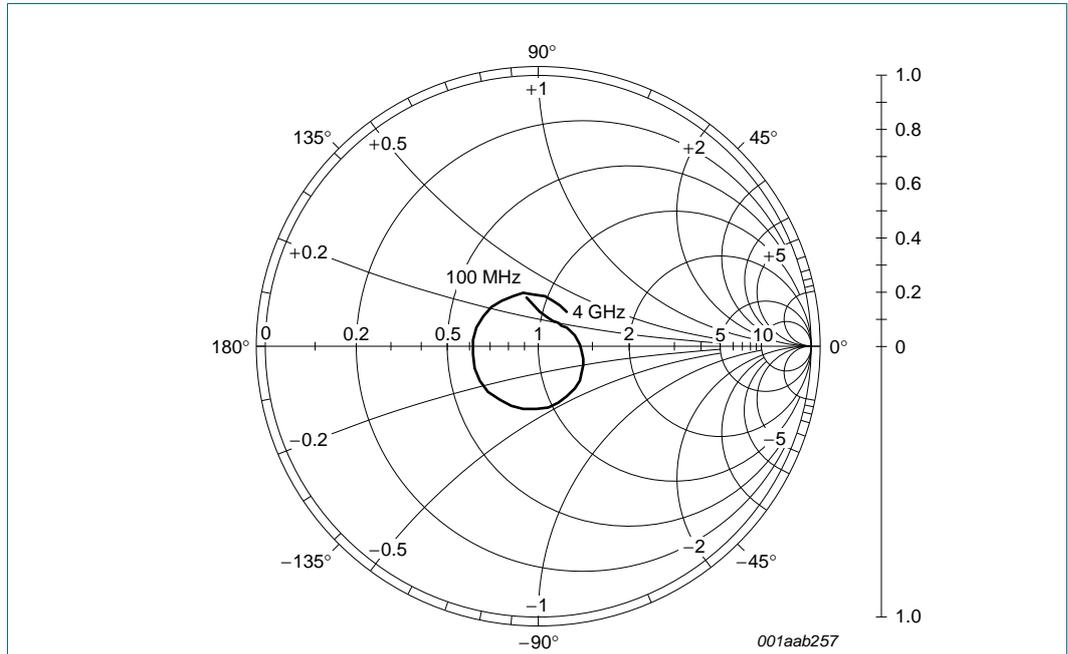
I_S = 15.9 mA; V_S = 5 V; P_D = −35 dBm; Z_o = 50 Ω.

Fig 6. **Input reflection coefficient (s_{11}); typical values.**
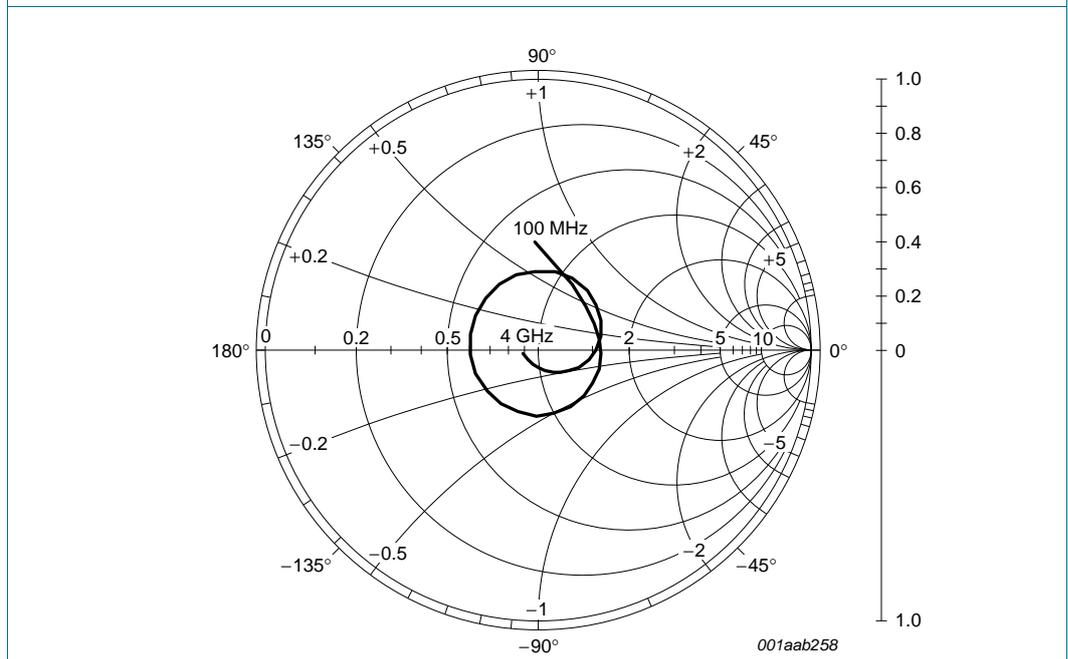
I_S = 15.9 mA; V_S = 5 V; P_D = −35 dBm; Z_o = 50 Ω.

Fig 7. **Output reflection coefficient (s_{22}); typical values.**

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$|s_{12}|^2$ (dB)
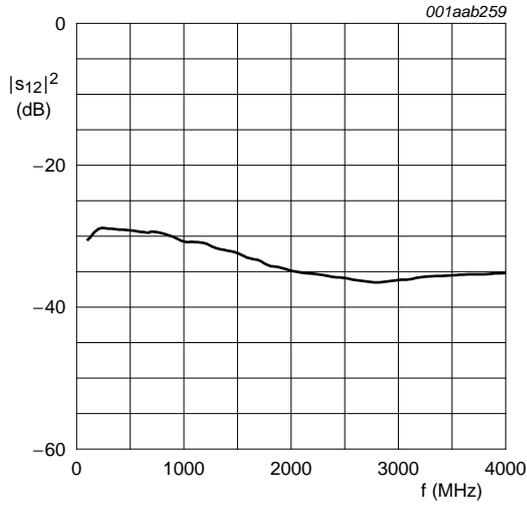
$I_S = 15.9$ mA; $V_S = 5$ V; $P_D = -35$ dBm; $Z_o = 50$ Ω.

Fig 8. Isolation ($|s_{12}|^2$) as a function of frequency; typical values.

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$|s_{21}|^2$ (dB)

$P_D = -35$ dBm; $Z_o = 50$ Ω.
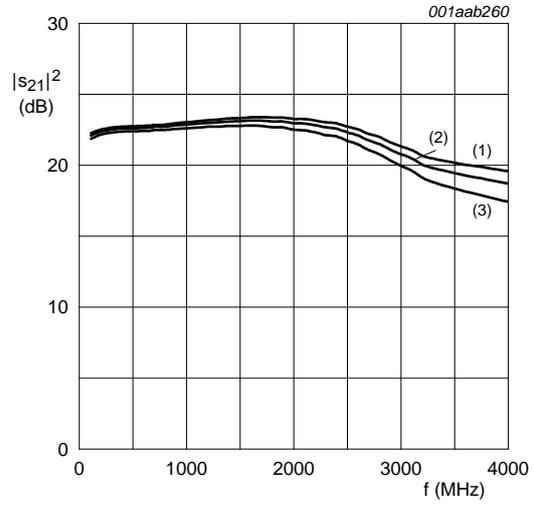
(1) $I_S = 19.5$ mA; $V_S = 5.5$ V.
(2) $I_S = 15.9$ mA; $V_S = 5$ V.
(3) $I_S = 12.4$ mA; $V_S = 4.5$ V.

Fig 9. Insertion gain ($|s_{21}|^2$) as a function of frequency; typical values.

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P_L (dBm)

f = 1 GHz; $Z_o = 50$ Ω.
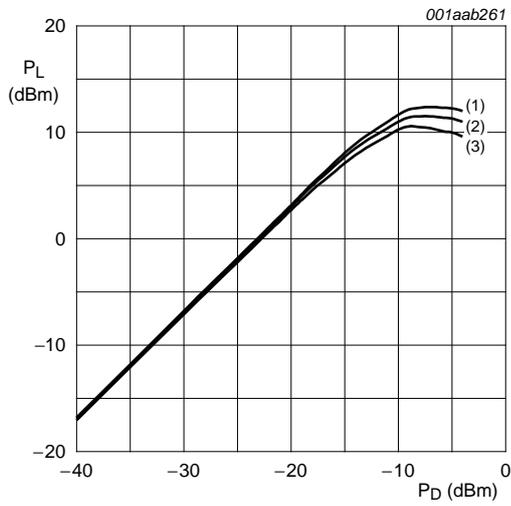
(1) $V_S = 5.5$ V.
(2) $V_S = 5$ V.
(3) $V_S = 4.5$ V.

Fig 10. Load power as a function of drive power at 1 GHz; typical values.

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P_L (dBm)
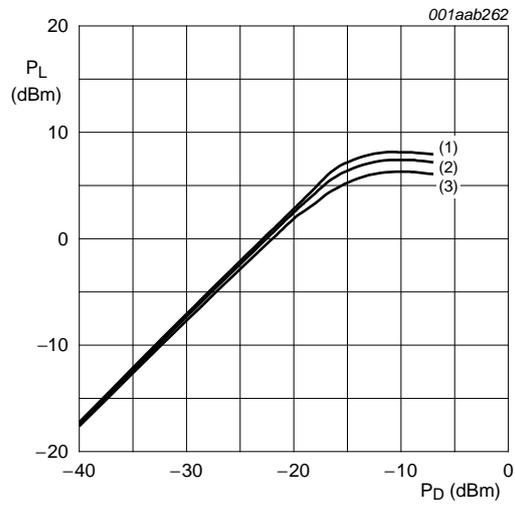
f = 2.2 GHz; $Z_o = 50$ Ω.

(1) $V_S = 5.5$ V.
(2) $V_S = 5$ V.
(3) $V_S = 4.5$ V.

Fig 11. Load power as a function of drive power at 2.2 GHz; typical values.

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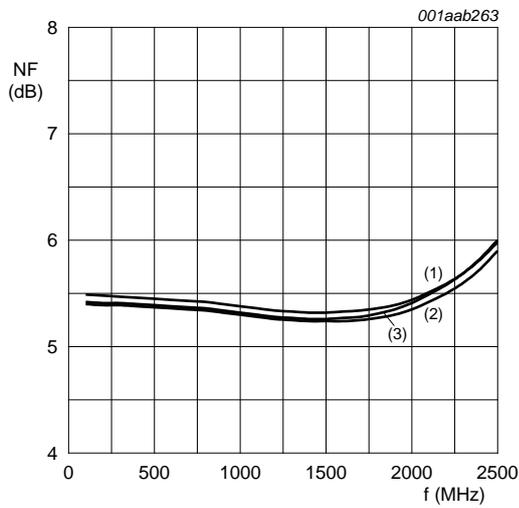
$Z_o = 50\ \Omega$.

(1) $I_S = 19.5$ mA; $V_S = 5.5$ V.

(2) $I_S = 15.9$ mA; $V_S = 5$ V.

(3) $I_S = 12.4$ mA; $V_S = 4.5$ V.

Fig 12. Noise figure as a function of frequency; typical values.
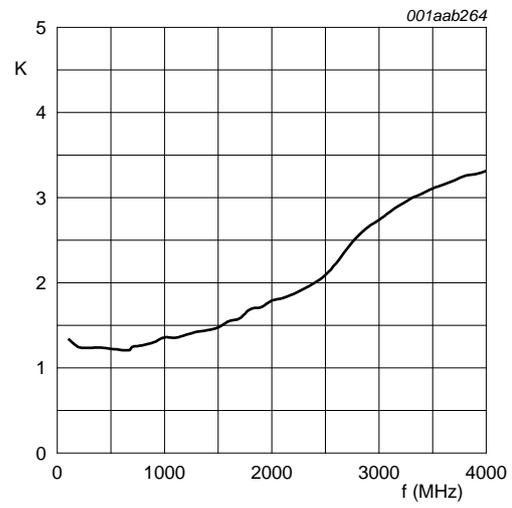
$I_S = 15.9$ mA; $V_S = 5$ V; $Z_o = 50\ \Omega$.

Fig 13. Stability factor as a function of frequency; typical values.

Table 8.   Scattering parameters

$V_S = 5$ V; $I_S = 15.9$ mA; $P_D = -35$ dBm; $Z_o = 50$ Ω; $T_{amb} = 25$ °C.

f (MHz)	s_{11}		s_{21}		s_{12}		s_{22}		K-factor
	Magnitude (ratio)	Angle (deg)	Magnitude (ratio)	Angle (deg)	Magnitude (ratio)	Angle (deg)	Magnitude (ratio)	Angle (deg)	
100	0.182562	102.7794	12.69581	13.48682	0.029472	28.74955	0.39239	91.48628	1.3
200	0.123465	87.55274	13.13419	−5.272917	0.035438	−2.202361	0.267851	62.37296	1.2
400	0.107855	58.58513	13.47149	−31.7377	0.035299	−22.54301	0.227252	24.6455	1.2
600	0.114731	40.14071	13.57901	−53.09631	0.033167	−43.06353	0.227993	−3.493572	1.3
800	0.130176	24.28555	13.67457	−73.60665	0.033194	−59.63503	0.234967	−31.11084	1.3
1000	0.144984	9.657616	13.91705	−94.01973	0.029047	−76.09972	0.239818	−60.54722	1.4
1200	0.160922	−7.518892	14.10949	−114.55	0.028188	−88.34045	0.242141	−91.56898	1.4
1400	0.179351	−23.35989	14.2808	−135.3117	0.025188	−101.2729	0.243087	−124.5484	1.4
1600	0.20199	−41.01349	14.3825	−156.7041	0.022257	−110.3342	0.24499	−158.6224	1.5
1800	0.218268	−60.71294	14.26935	−178.3843	0.019611	−121.0192	0.255598	167.5983	1.7
2000	0.233965	−81.48254	14.0667	160.1504	0.018087	−127.6765	0.269829	136.117	1.8
2200	0.242904	−103.1109	13.83968	138.2379	0.017203	−137.8213	0.283613	106.0987	1.9
2400	0.246576	−125.52	13.46447	115.7594	0.016318	−138.8717	0.29058	77.95189	2.0
2600	0.249069	−148.8707	12.74638	93.38644	0.015514	−147.6622	0.281505	50.68612	2.2
2800	0.243665	−172.646	11.87558	71.02792	0.014954	−152.1988	0.25135	24.40624	2.5
3000	0.233266	163.9035	10.94049	50.42722	0.015522	−163.8718	0.211425	−0.674037	2.7
3200	0.222055	140.7754	10.05626	30.75908	0.016261	−170.5637	0.165534	−23.9944	2.9
3400	0.207486	117.0531	9.576357	11.98315	0.016664	−176.5407	0.118726	−46.28101	3.0
3600	0.191654	94.64431	9.199166	−7.677643	0.016982	176.9385	0.083354	−72.36691	3.2
3800	0.175783	71.9551	8.912598	−27.73098	0.017094	165.8227	0.058549	−109.9804	3.3
4000	0.163768	49.89436	8.618058	−48.90874	0.017414	157.6095	0.055225	−163.7132	3.3

9. Package outline

Plastic surface-mounted package; 6 leads   **SOT363**

DIMENSIONS (mm are the original dimensions)

UNIT	A	A₁ max	bp	c	D	E	e	e₁	H_E	L_p	Q	v	w	y
mm	1.1 0.8	0.1	0.30 0.20	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.25 0.15	0.2	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	**JEDEC**	**JEITA**			
SOT363			SC-88			04-11-08 06-03-16
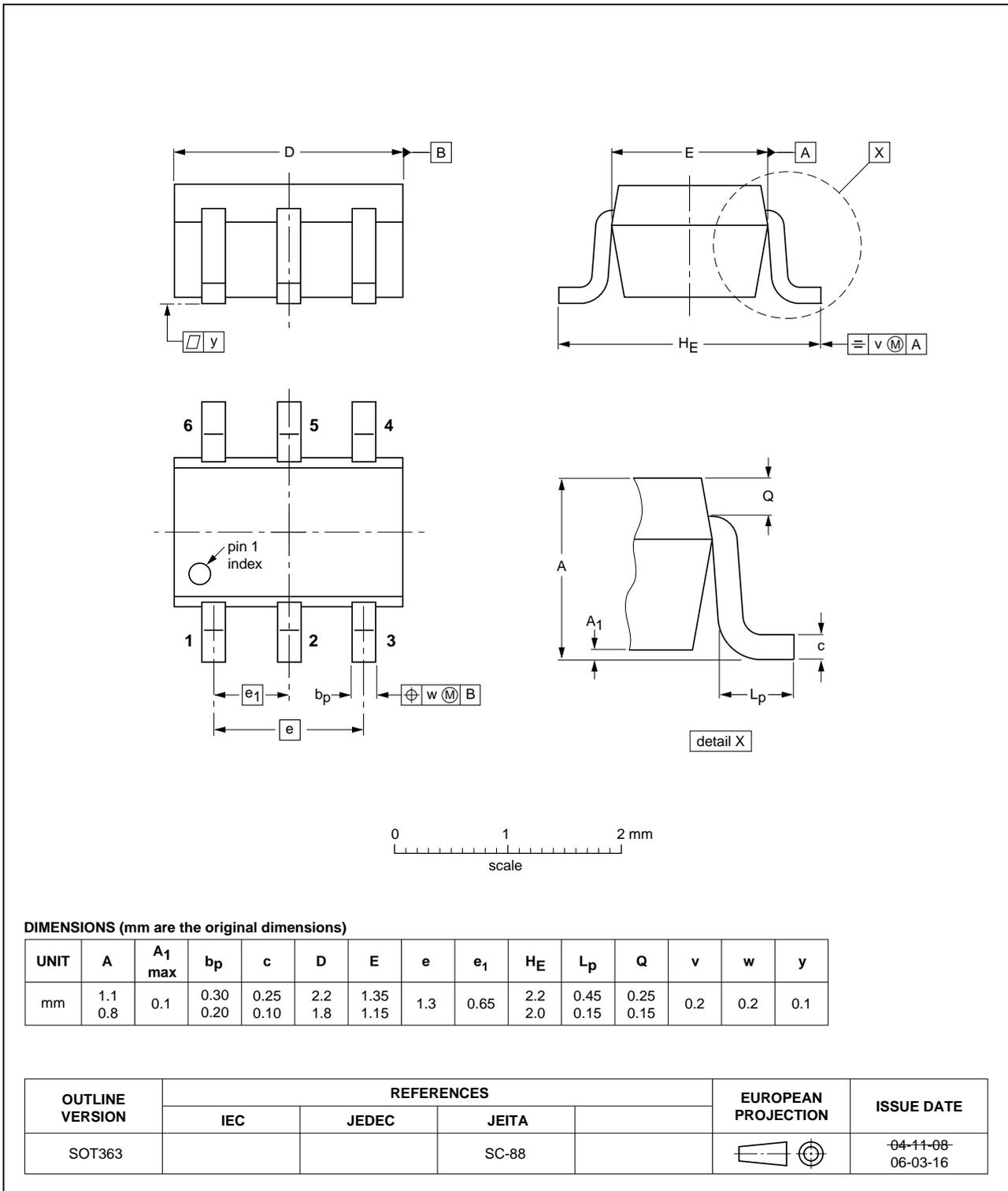
Fig 14. Package outline; SOT363 (SC-88).

10. Revision history

Table 9. **Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BGA2716 v.3	20110908	Product data sheet	-	BGA2716 v.2
Modifications:	• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. • Legal texts have been adapted to the new company name where appropriate. • Package outline drawings have been updated to the latest version.			
BGA2716 v.2 (9397 750 13292)	20040924	Product data sheet	-	BGA2716_N v.1
BGA2716_N v.1 (9397 750 12827)	20040202	Preliminary data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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13. Contents